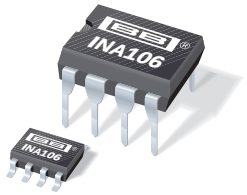
INA106



SBOS152A – AUGUST 1987 – REVISED OCTOBER 2003

Precision Gain = 10 DIFFERENTIAL AMPLIFIER

FEATURES

- ACCURATE GAIN: ±0.025% max
- HIGH COMMON-MODE REJECTION: 86dB min
- NONLINEARITY: 0.001% max
- EASY TO USE
- PLASTIC 8-PIN DIP, SO-8 SOIC PACKAGES

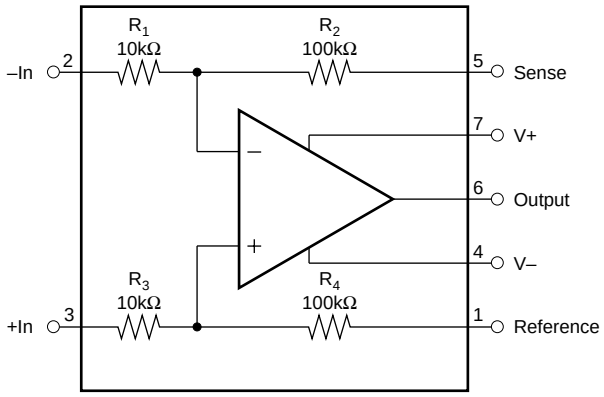
APPLICATIONS

- G = 10 DIFFERENTIAL AMPLIFIER
- G = +10 AMPLIFIER
- G = –10 AMPLIFIER
- G = +11 AMPLIFIER
- INSTRUMENTATION AMPLIFIER

DESCRIPTION

The INA106 is a monolithic Gain = 10 differential amplifier consisting of a precision op amp and on-chip metal film resistors. The resistors are laser trimmed for accurate gain and high common-mode rejection. Excellent TCR tracking of the resistors maintains gain accuracy and common-mode rejection over temperature.

The differential amplifier is the foundation of many commonly used circuits. The INA106 provides this precision circuit function without using an expensive resistor network. The INA106 is available in 8-pin plastic DIP and SO-8 surface-mount packages.



SPECIFICATIONS

ELECTRICAL

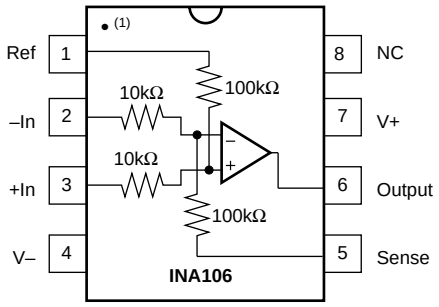
At +25°C, V_S = ±15V, unless otherwise specified.

PARAMETER	CONDITIONS	INA106KP, U			UNITS
		MIN	TYP	MAX	
GAIN					
Initial[1]			10		V/V
Error			0.01	0.025	%
vs Temperature			–4		ppm/°C
Nonlinearity[2]			0.0002	0.001	%
OUTPUT					
Related Voltage	I_O = +20mA, –5mA	10	12		V
Rated Current	V_O = 10V	+20, –5			mA
Impedance			0.01		Ω
Current Limit	To Common		+40/–10		mA
Capacitive Load	Stable Operation		1000		pF
INPUT					
Impedance	Differential		10		kΩ
	Common-Mode		110		kΩ
Voltage Range	Differential	±1			V
	Common-Mode	±11			V
Common-Mode Rejection[3]	$T_A = T_{MIN}$ to T_{MAX}	86	100		dB
OFFSET VOLTAGE	RTI[4]				
Initial			50	200	µV
vs Temperature			0.2		µV/°C
vs Supply	$\pm V_S$ = 6V to 18V		1	10	µV/V
vs Time			10		µV/mo
NOISE VOLTAGE	RTI[5]				
f_B = 0.01Hz to 10Hz			1		µVp-p
f_O = 10kHz			30		nV/√Hz
DYNAMIC RESPONSE					
Small Signal	–3dB		5		MHz
Full Power BW	V_O = 20Vp-p	30	50		kHz
Slew Rate		2	3		V/µs
Settling Time: 0.1%	V_O = 10V Step		5		µs
0.01%	V_O = 10V Step		10		µs
0.01%	V_{CM} = 10V Step, V_{DIFF} = 0V		5		µs
POWER SUPPLY					
Rated			±15		V
Voltage Range	Derated Performance	±5		±18	V
Quiescent Current	V_O = 0V		±1.5	±2	mA
TEMPERATURE RANGE					
Specification		0		+70	°C
Operation		–40		+85	°C
Storage		–65		+150	°C

NOTES: (1) Connected as difference amplifier (see Figure 1). (2) Nonlinearity is the maximum peak deviation from the best-fit straight line as a percent of full-scale peak-to-peak output. (3) With zero source impedance (see "Maintaining CMR" section). (4) Includes effects of amplifiers's input bias and offset currents. (5) Includes effect of amplifier's input current noise and thermal noise contribution of resistor network.

PIN CONFIGURATION

Top View **DIP/SOIC**



NOTE: (1) Pin 1 indentifier for SO-8 package. Model number identification may be abbreviated on SO-8 package due to limited available space.

ABSOLUTE MAXIMUM RATINGS

Power Supply Voltage	±18V
Input Voltage Range	$\pm V_S$
Operating Temperature Range: P, U	–40°C to +85°C
Storage Temperature Range	–40°C to +85°C
Lead Temperature (soldering, 10s): P	+300°C
Wave Soldering (3s, max) U	+260°C
Output Short Circuit to Common	Continuous

NOTE: (1) Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods may affect device reliability.

ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

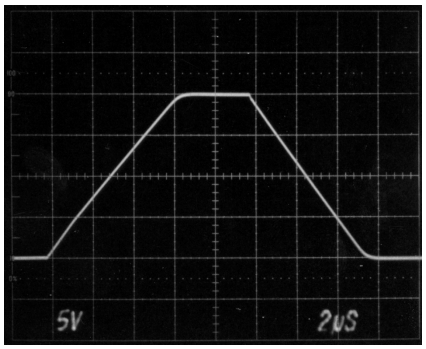
PACKAGE/ORDERING INFORMATION

For the most current package and ordering information, see the Package Option Addendum located at the end of this data sheet.

TYPICAL PERFORMANCE CURVES

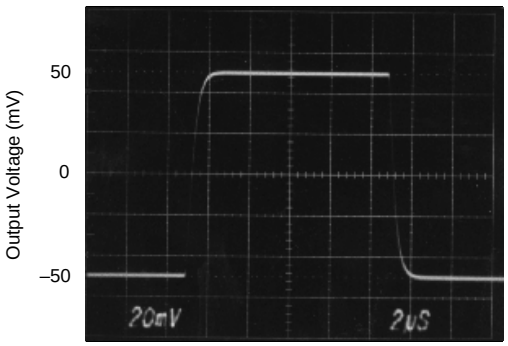
At T_A = +25°C, V_S = ±15V, unless otherwise noted.

STEP RESPONSE



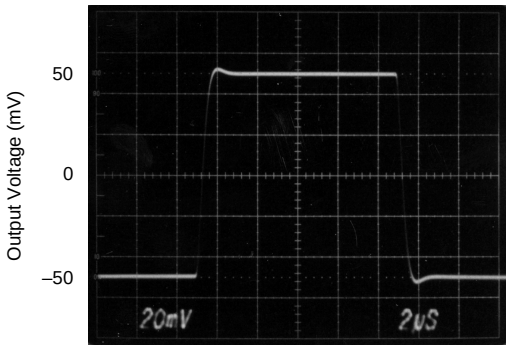
2µs/div

SMALL SIGNAL RESPONSE
(No Load)



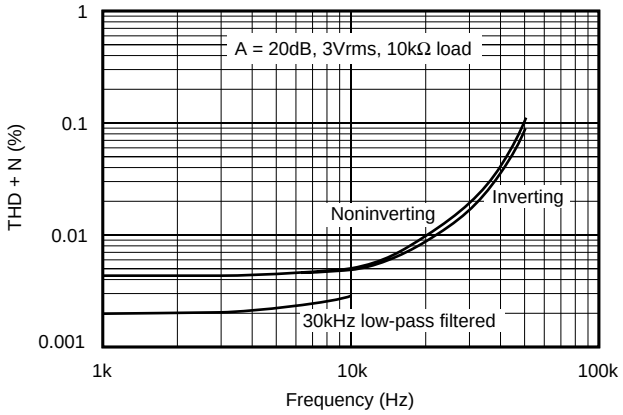
2µs/div

SMALL SIGNAL RESPONSE
(R_{LOAD} = ∞, C_{LOAD} = 100pF)

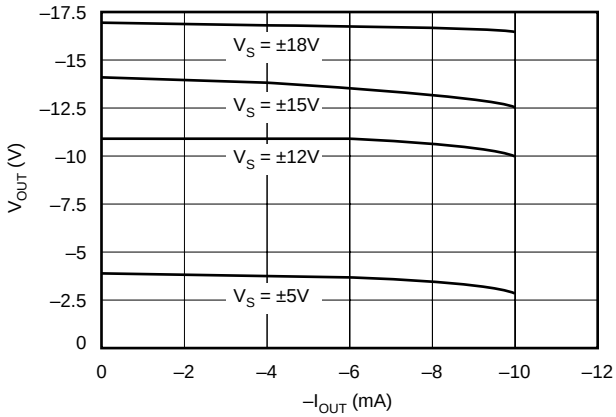


2µs/div

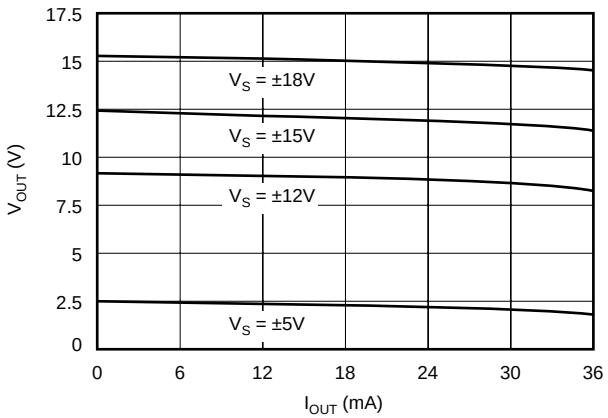
TOTAL HARMONIC DISTORTION AND NOISE
vs FREQUENCY



MAXIMUM V_{OUT} vs I_{OUT}
(Negative Swing)

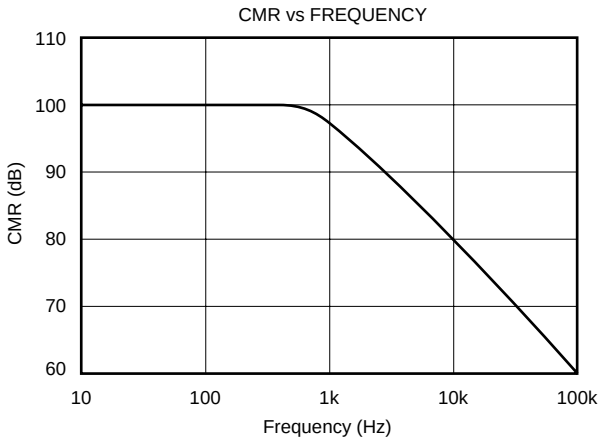


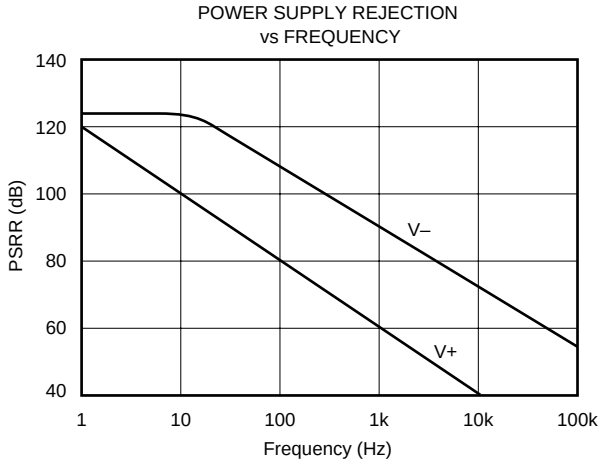
MAXIMUM V_{OUT} vs I_{OUT}
(Positive Swing)



TYPICAL PERFORMANCE CURVES (CONT)

At T_A = +25°C, V_S = ±15V, unless otherwise noted.





APPLICATIONS INFORMATION

Figure 1 shows the basic connections required for operation of the INA106. Power supply bypass capacitors should be connected close to the device pins as shown.

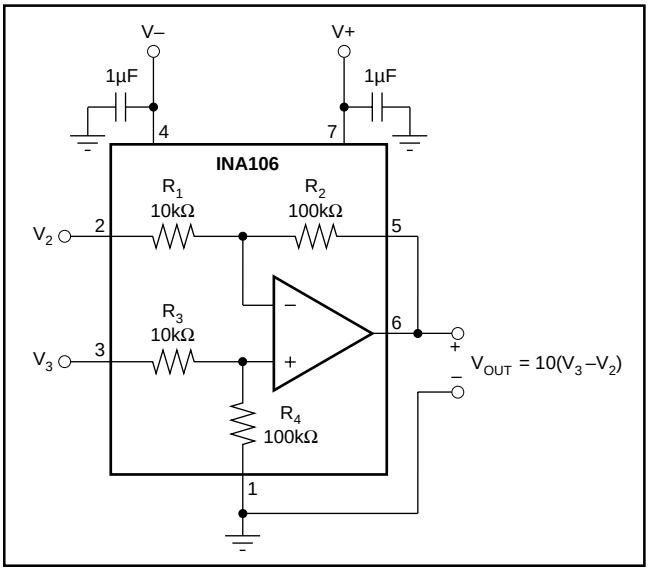


FIGURE 1. Basic Power Supply and Signal Connections.

The differential input signal is connected to pins 2 and 3 as shown. The source impedance connected to the inputs must be equal to assure good common-mode rejection. A 5Ω mismatch in source impedance will degrade the common-mode rejection of a typical device to approximately 86dB. If the source has a known source impedance mismatch, an additional resistor in series with one input can be used to preserve good common-mode rejection.

The output is referred to the output reference terminal (pin 1) which is normally grounded. A voltage applied to the Ref terminal will be summed with the output signal. The source impedance of a signal applied to the Ref terminal should be less than 10Ω to maintain good common-mode rejection.

Figure 2 shows a voltage applied to pin 1 to trim the offset voltage of the INA106. The known 100Ω source impedance of the trim circuit is compensated by the 10Ω resistor in series with pin 3 to maintain good CMR.

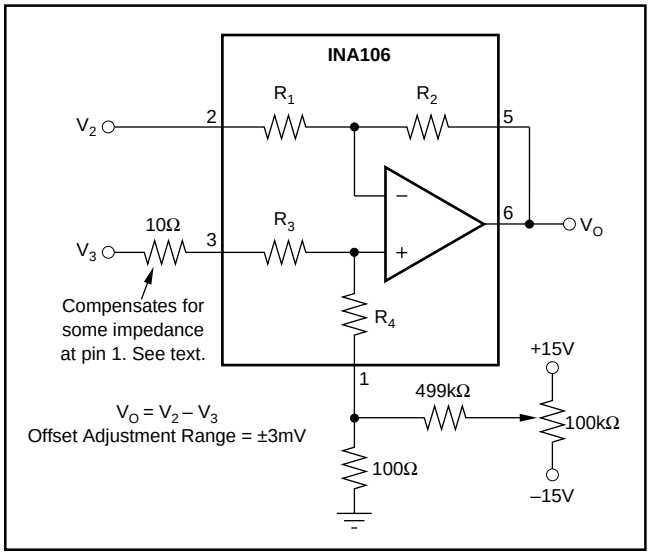


FIGURE 2. Offset Adjustment.

Referring to Figure 1, the CMR depends upon the match of the internal R_4/R_3 ratio to the R_1/R_2 ratio. A CMR of 106dB requires resistor matching of 0.005%. To maintain high CMR over temperature, the resistor TCR tracking must be better than 2ppm/°C. These accuracies are difficult and expensive to reliably achieve with discrete components.

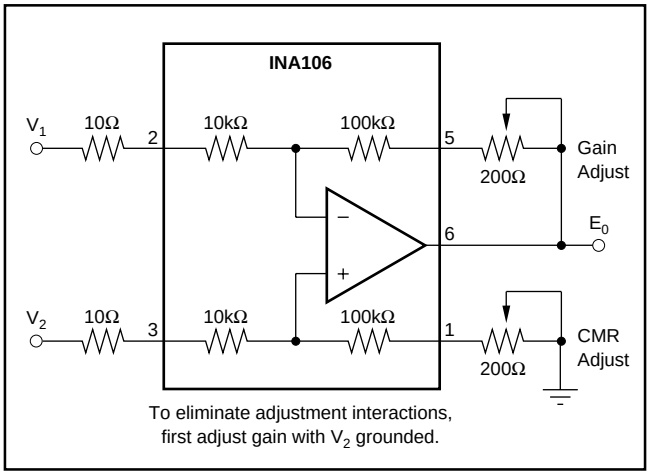


FIGURE 3. Difference Amplifier with Gain and CMR Adjust.

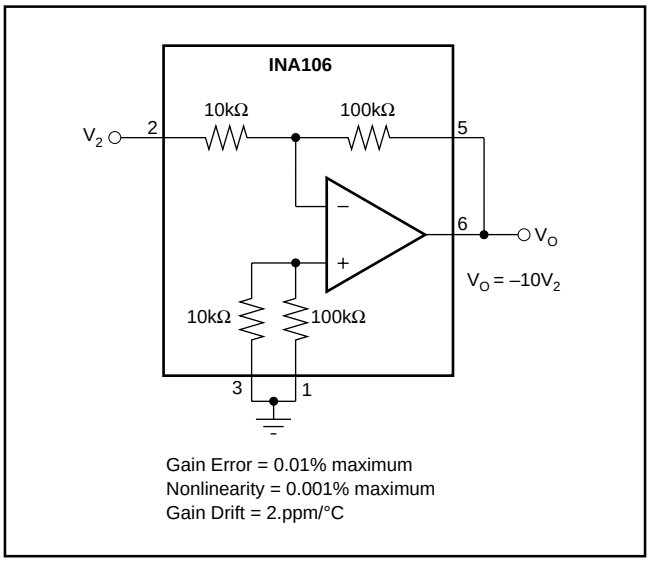


FIGURE 4. Precision G = –10 Inverting Amplifier.

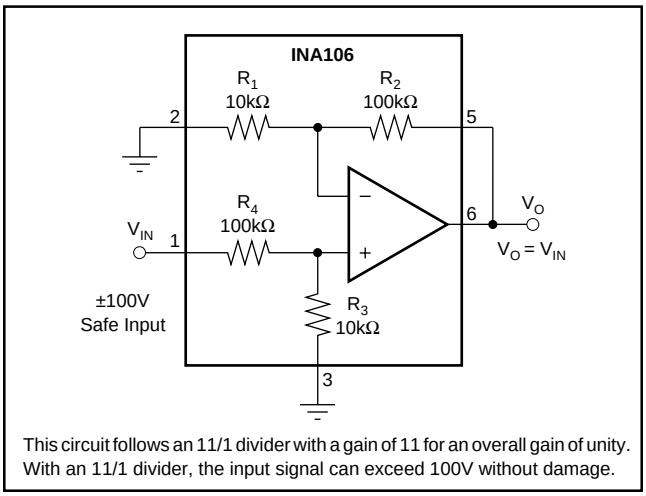
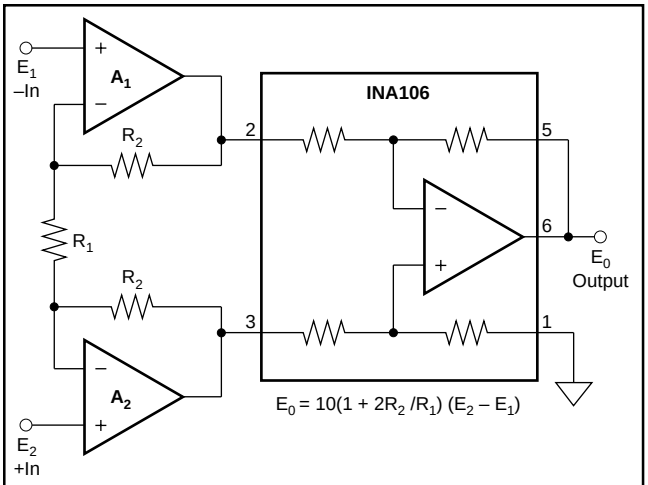


FIGURE 5. Voltage Follower with Input Protection.



To make a high performance high gain instrumentation amplifier, the INA106 can be combined with state-of-the-art op amps. For low source impedance applications, OPA37s will give the best noise, offset, and temperature drift. At source impedances above about 10kΩ, the bias current noise of the OPA37 reacting with input impedance degrades noise. For these applications, use an OPA111 or a dual OPA2111 FET input op amp for lower noise. For an electrometer grade IA, use the OPA128—see table below.

Using the INA106 for the difference amplifier also extends the input common-mode range of the instrumentation amplifier to ±10V. A conventional IA with a unity-gain difference amplifier has an input common-mode range limited to ±5V for an output swing of ±10V. This is because a unity-gain difference amp needs ±5V at the input for 10V at the output, allowing only 5V additional for common-mode.

A_1, A_2	R_1 (Ω)	R_2 (kΩ)	GAIN (V/V)	CMRR (dB)	I_b (pA)	NOISE AT 1kHz (nV/ $\sqrt{Hz}$)
OPA37A	50.5	2.5	1000	128	40000	4
OPA111B	202	10	1000	110	1	10
OPA128LM	202	10	1000	118	0.075	38

FIGURE 6. Precision Instrumentation Amplifier.

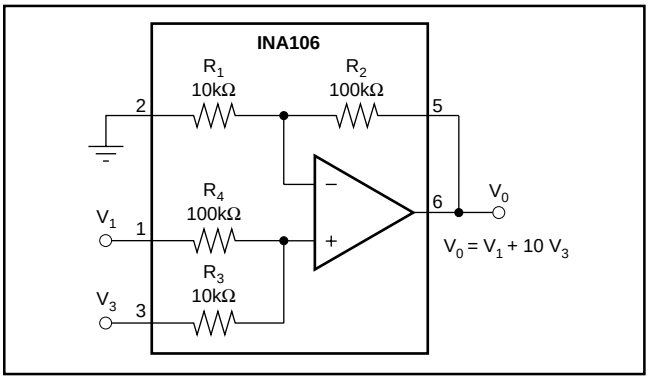


FIGURE 7. Precision Summing Amplifier.

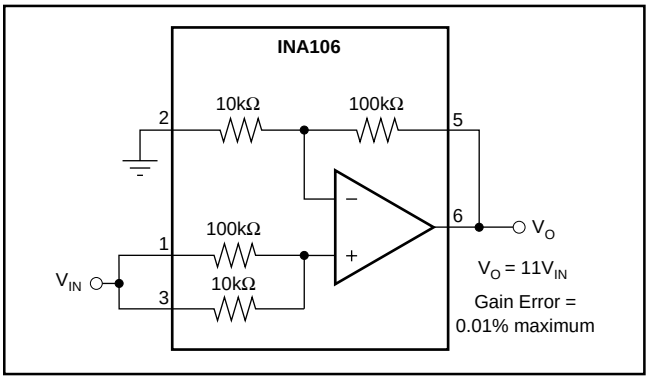


FIGURE 8. Precision G = 11 Buffer.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
INA106KP	ACTIVE	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	INA106KP	Samples
INA106U	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU-DCC	Level-3-260C-168 HR		INA 106U	Samples
INA106U/2K5	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-3-260C-168 HR		INA 106U	Samples
INA106UE4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU-DCC	Level-3-260C-168 HR		INA 106U	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

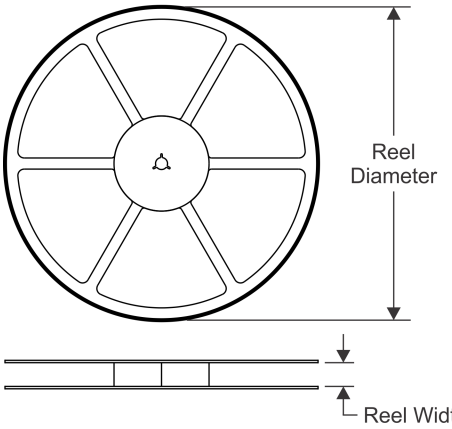
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals.
TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

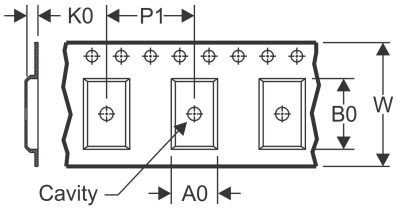
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

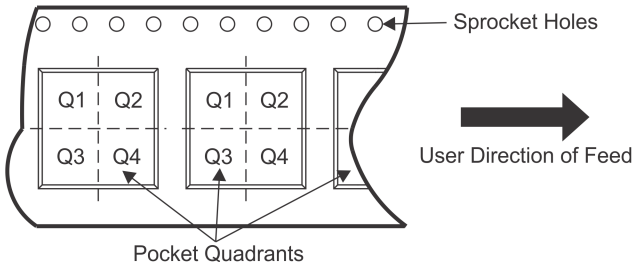


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

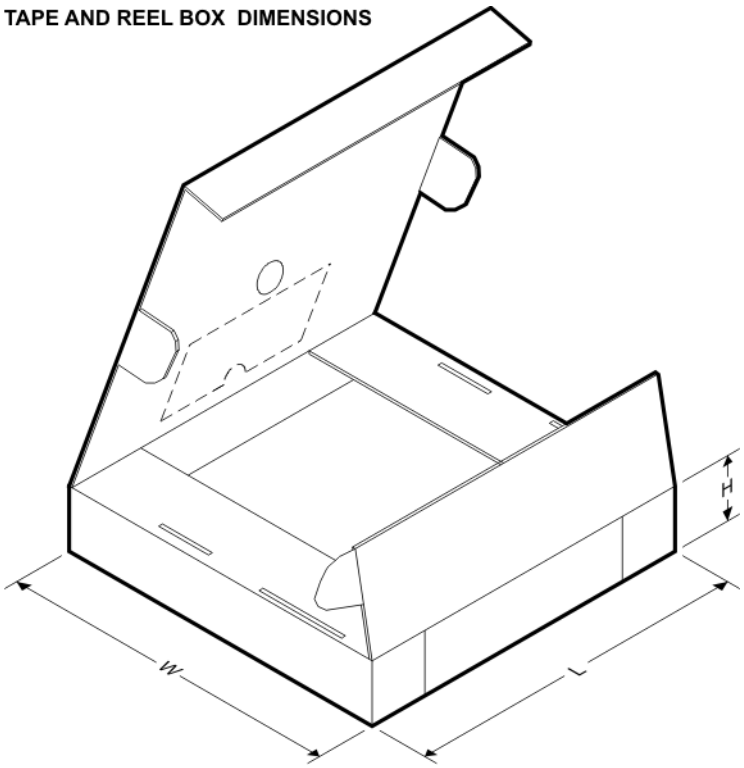
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA106U/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

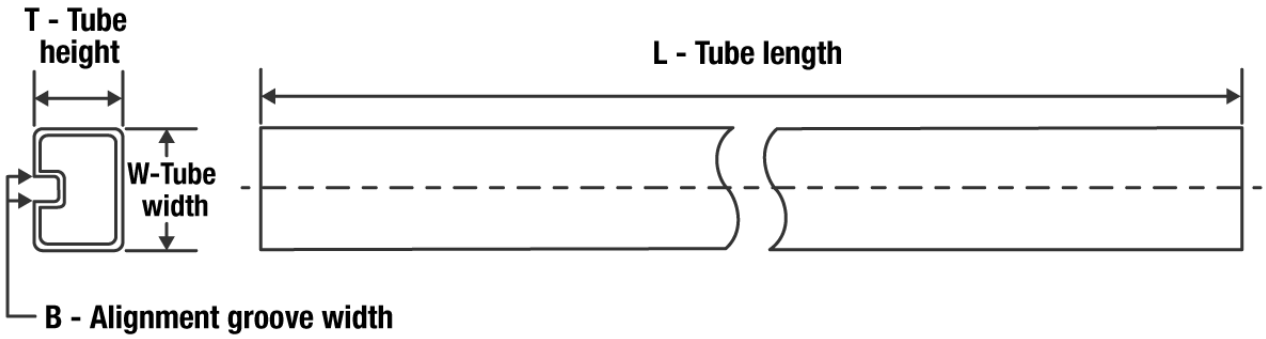
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

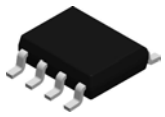
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA106U/2K5	SOIC	D	8	2500	367.0	367.0	35.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
INA106KP	P	PDIP	8	50	506	13.97	11230	4.32
INA106U	D	SOIC	8	75	506.6	8	3940	4.32
INA106UE4	D	SOIC	8	75	506.6	8	3940	4.32

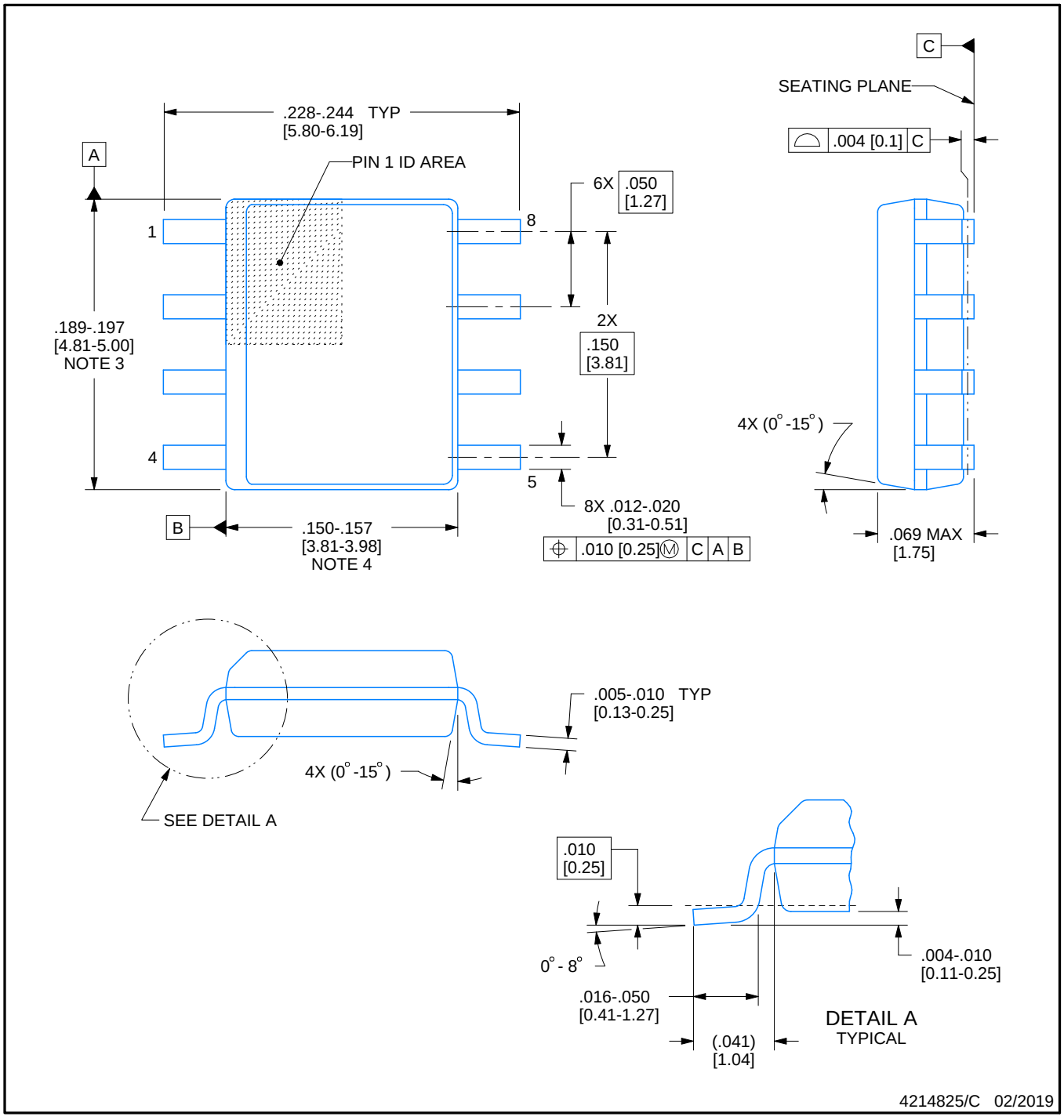


PACKAGE OUTLINE

D0008A

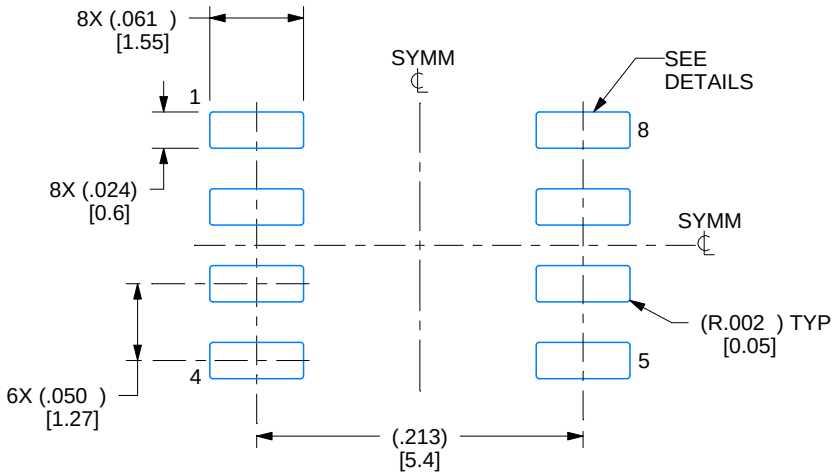
SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

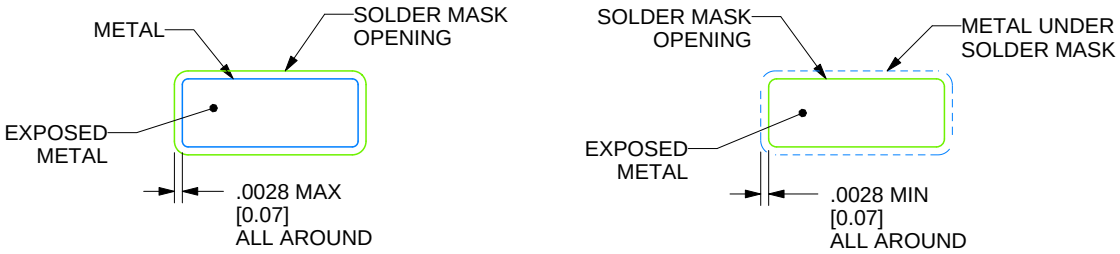


NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

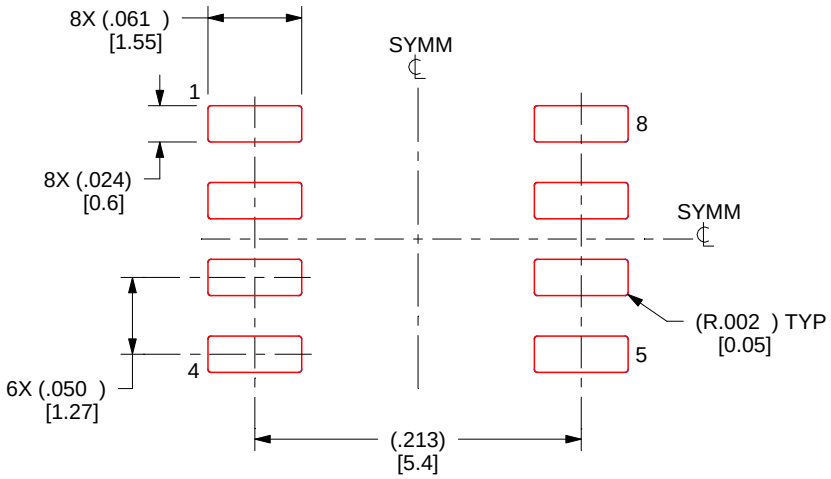
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



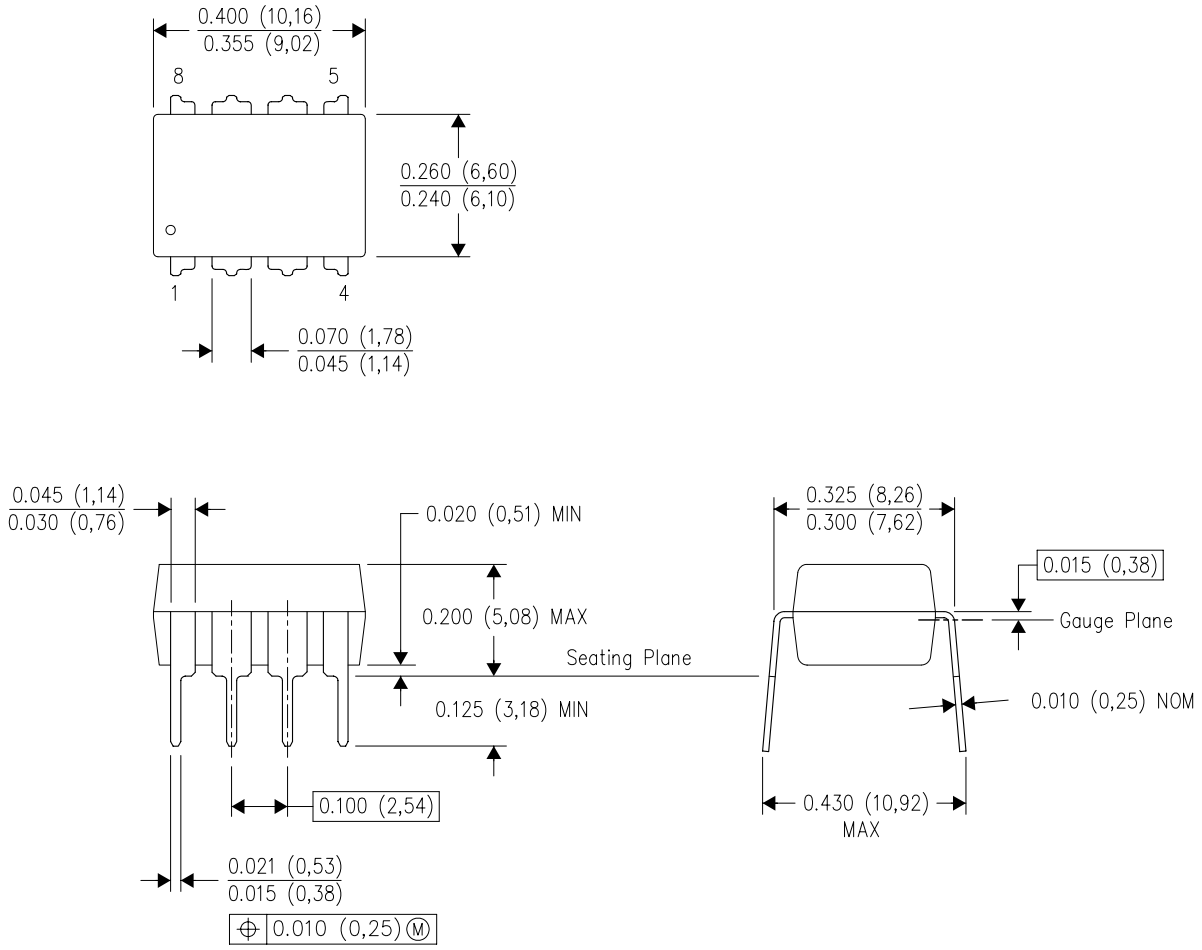
SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R–PDIP–T8) PLASTIC DUAL–IN–LINE PACKAGE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001 variation BA.

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